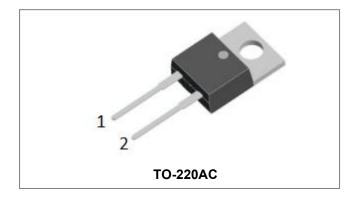
SMC DIDDE SOLUTIONS

19TQ015CJ

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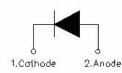
19TQ015CJ SCHOTTKY RECTIFIER



Features

- 100 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	15	V
Average Rectified Forward Current (Per Device)	I _{F (AV)}	50% duty cycle @Tc=75°C, rectangular wave form	19	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	120	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 19A, Pulse, T _A = 25 °C @ 38A, Pulse, T _A = 25 °C	0.31 0.37	0.36 0.46	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	3.5	10.5	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz		2500	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 µs, duty cycle < 2%</p>

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RoHS 🗭

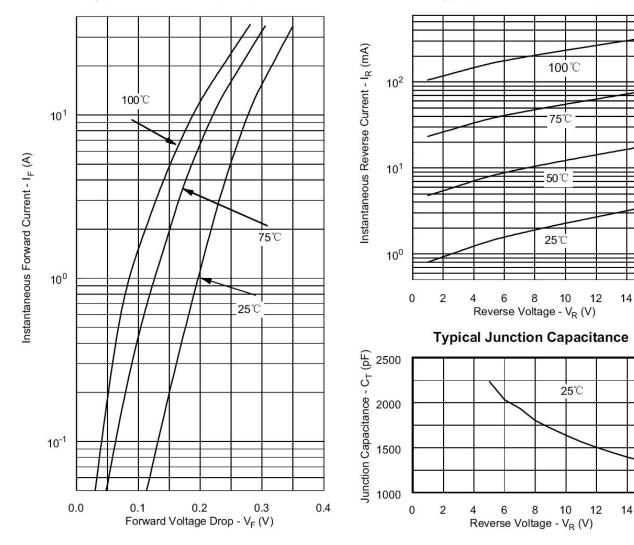
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Thermal-Mechanical Specifications:

Characteristics	Symbol Condition		Specification	Units
Junction Temperature	TJ	-	-55 to +100	°C
Storage Temperature	T _{stg}	-	-55 to +100	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

Ratings and Characteristics Curves



Typical Forward Characteristics

Typical Reverse Characteristics

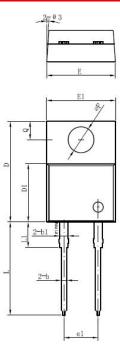
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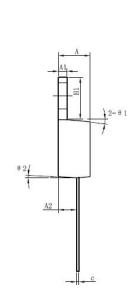


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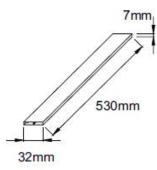
Mechanical Dimensions TO-220AC



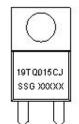


Symbol	Dimensions in millimeters				
	Min.	Typical	Max.		
Α	4.47	4.70	4.85		
A1	1.17	1.27	1.37		
A2	2.52	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
D	14.64	14.94	15.24		
D1	8.50	8.07	8.90		
E	10.01	10.16	10.31		
E1	9.98	10.18	10.38		
e1	4.98	5.08	5.18		
H1	6.04	6.24	6.44		
L	13.00	13.86	14.08		
L1	3.56	3.80	3.96		
ΦΡ	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		5°			
Θ2		4°			
Θ3		4°			

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

19TQ015CJ SSG YY WW

L

- 5CJ = Part Name = SSG
- = Year
 - = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
19TQ015CJ	TO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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